RoHS

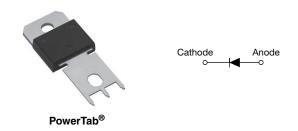
**HALOGEN** 

FREE



Vishay Semiconductors

# Ultrafast Soft Recovery Diode, 80 A FRED Pt®



#### **LINKS TO ADDITIONAL RESOURCES**



| PRIMARY CHARACTERISTICS          |                       |  |  |  |
|----------------------------------|-----------------------|--|--|--|
| I <sub>F(AV)</sub>               | 80 A                  |  |  |  |
| V <sub>R</sub>                   | 200 V                 |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.77 V                |  |  |  |
| t <sub>rr</sub> (typ.)           | See recovery table    |  |  |  |
| T <sub>J</sub> max.              | 175 °C                |  |  |  |
| Package                          | PowerTab <sup>®</sup> |  |  |  |
| Circuit configuration            | Single                |  |  |  |

#### **FEATURES**

- · Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **BENEFITS**

- · Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing
- Reduced parts count

### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

#### **MECHANICAL DATA**

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating

Terminal: nickel plated screwable

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                         |             |       |
|---|-----------------------------------|-------------------------|-------------|-------|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS         | MAX.        | UNITS |
| Cathode to anode voltage                    | $V_R$                             |                         | 200         | V     |
| Continuous forward current                  | I <sub>F(AV)</sub>                | T <sub>C</sub> = 131 °C | 80          |       |
| Single pulse forward current                | I <sub>FSM</sub>                  | T <sub>C</sub> = 25 °C  | 800         | Α     |
| Maximum repetitive forward current          | I <sub>FRM</sub>                  | Square wave, 20 kHz     | 160         |       |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                         | -55 to +175 | °C    |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                     |  |     |      |      |       |
|--|-------------------------------------|--|-----|------|------|-------|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS MIN                                    |     | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage  | V <sub>BR</sub> ,<br>V <sub>r</sub> | I <sub>R</sub> = 50 μA                                 | 200 | -    | -    | V     |
| Forward voltage  | V <sub>F</sub>                      | I <sub>F</sub> = 80 A                                  | -   | 0.94 | 1.10 | V     |
|  | ٧F                                  | I <sub>F</sub> = 80 A, T <sub>J</sub> = 175 °C         | -   | 0.77 | 0.88 |       |
| Reverse leakage current I <sub>R</sub>   |                                     | $V_R = V_R$ rated                                      | -   | -    | 50   | μA    |
|  |                                     | $T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$ | -   | -    | 2    | mA    |
| Junction capacitance   | C <sub>T</sub>                      | V <sub>R</sub> = 200 V                                 | -   | 89   | -    | pF    |
| Series inductance  | L <sub>S</sub>                      | Measured lead to lead 5 mm from package body           | ı   | 3.5  | -    | nH    |



## Vishay Semiconductors

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                       |  |  |      |      |      |       |
|---|---------------------------------------|--|--|------|------|------|-------|
| PARAMETER   | SYMBOL                                | TEST CONDITIONS  |  | MIN. | TYP. | MAX. | UNITS |
| Boyaraa raaayany tima   | +                                     | T <sub>J</sub> = 25 °C   |  | -    | 40   | -    | no    |
| Reverse recovery time   | Reverse recovery time t <sub>rr</sub> | T <sub>J</sub> = 125 °C  |  | -    | 75   | -    | ns    |
| Peak recovery current I <sub>RRM</sub>  | T <sub>J</sub> = 25 °C                | $I_F = 80 \text{ A}$<br>$V_R = 160 \text{ V}$<br>$dI_F/dt = 200 \text{ A/}\mu\text{s}$ | -                                      | 4.0  | -    | ^    |       |
|   | T <sub>J</sub> = 125 °C               |  | -                                      | 8.8  | -    | A    |       |
| Reverse recovery charge   | 0                                     | T <sub>J</sub> = 25 °C   | αι <sub>-</sub> /αι – 200 <i>Α</i> /μ3 | -    | 75   | -    | nC    |
|   | $Q_{rr}$                              | T <sub>J</sub> = 125 °C  |  | -    | 310  | -    | 110   |

| THERMAL - MECHANICAL SPECIFICATIONS      |                   |  |             |      |             |                     |
|--|-------------------|--|-------------|------|-------------|---------------------|
| PARAMETER                                | SYMBOL            | TEST CONDITIONS                            | MIN.        | TYP. | MAX.        | UNITS               |
| Thermal resistance, junction to case     | R <sub>thJC</sub> |  | -           | -    | 0.5         | °C/W                |
| Thermal resistance, junction to heatsink | R <sub>thCS</sub> | Mounting surface, flat, smooth and greased | -           | 0.2  | -           | C/VV                |
| Weight                                   |                   |  | -           | -    | 5.02        | g                   |
| Mounting torque                          |                   |  | 1.2<br>(10) | -    | 2.4<br>(20) | N · m<br>(lbf · in) |
| Marking device                           |                   | Case style PowerTab®                       |             | 80EB | U02H        |                     |

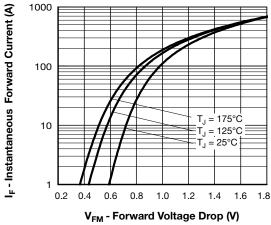


Fig. 1 - Maximum Forward Voltage Drop Characteristics

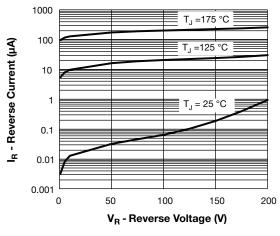


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

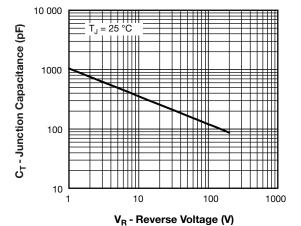


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

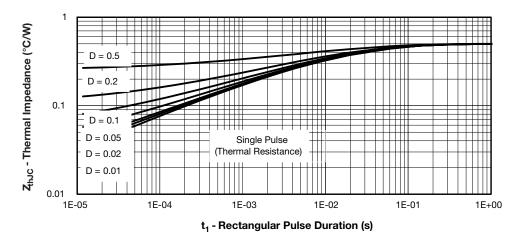


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

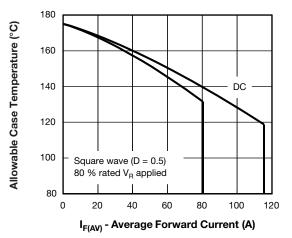


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

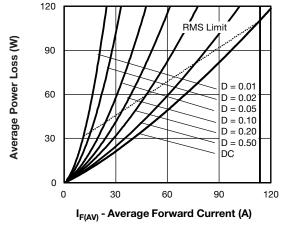


Fig. 6 - Forward Power Loss Characteristics

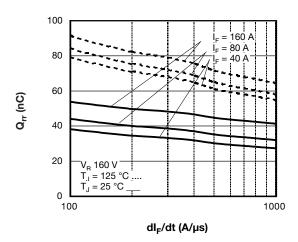


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

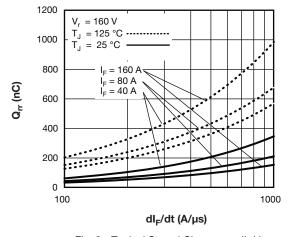
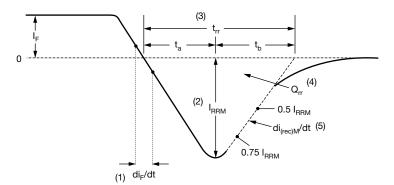


Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$ 

### Note

<sup>(1)</sup> Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>

## Vishay Semiconductors



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

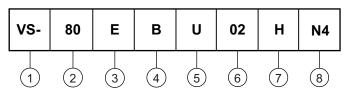
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

**Device code** 



- Vishay Semiconductors product
- 2 Current rating (80 = 80 A)
- 3 Single diode
- 4 PowerTab®
- 5 Ultrafast recovery
- 6 Voltage rating (02 = 200 V)
- 7 H = AEC-Q101 qualified
- 8 Environmental digit:

N4 = Halogen-free, RoHS-compliant and totally lead (Pb)-free

| ORDERING INFORMATION (Example) |               |                         |  |  |
|--------------------------------|---------------|-------------------------|--|--|
| PREFERRED P/N                  | BASE QUANTITY | PACKAGING DESCRIPTION   |  |  |
| VS-80EBU02HN4                  | 25/tube       | Antistatic plastic tube |  |  |

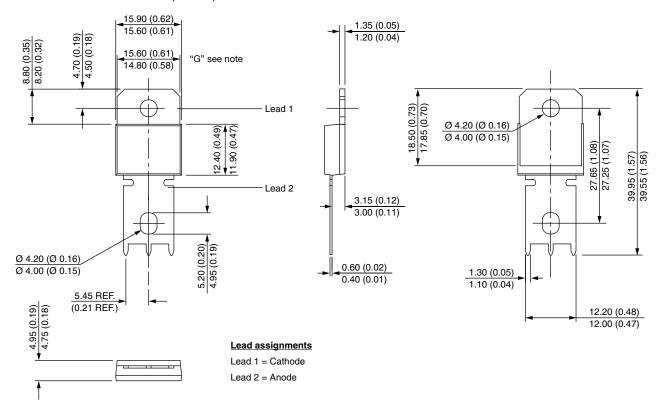
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?95240 |  |  |  |
| Part marking information   | www.vishay.com/doc?95467 |  |  |  |
| Application note           | www.vishay.com/doc?95179 |  |  |  |



## Vishay Semiconductors

## PowerTab®

### **DIMENSIONS** in millimeters (inches)



#### Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.